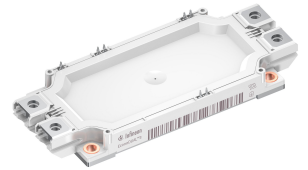


## Final datasheet

### EconoDUAL™3 module with TRENCHSTOP™ IGBT7 and emitter controlled 7 diode and PressFIT / NTC

#### Features

- Electrical features
  - $V_{CES} = 1700\text{ V}$
  - $I_{C\text{ nom}} = 900\text{ A} / I_{CRM} = 1800\text{ A}$
  - Integrated temperature sensor
  - High current density
  - Low  $V_{CE,sat}$
  - Overload operation up to  $175^{\circ}\text{C}$
  - TRENCHSTOP™ IGBT7
  - $V_{CE,sat}$  with positive temperature coefficient
  - Suitable Infineon gate drivers can be found under <https://www.infineon.com/gdfinder>
- Mechanical features
  - High power density
  - Isolated base plate
  - PressFIT contact technology
  - Standard housing
  - Direct-cooled base plate



#### Potential applications

- High-power converters
- Medium-voltage converters
- Motor drives
- Wind turbines

#### Product validation

- Qualified for industrial applications according to the relevant tests of IEC 60747, 60749 and 60068

#### Description

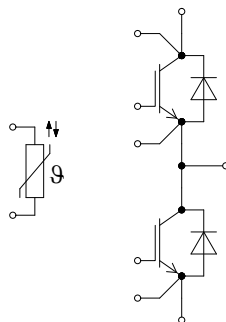


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## 1 Package

**Table 1** Insulation coordination

| Parameter                           | Symbol          | Note or test condition                         | Values    | Unit |
|-------------------------------------|-----------------|------------------------------------------------|-----------|------|
| Isolation test voltage              | $V_{ISOL}$      | RMS, $f = 50 \text{ Hz}$ , $t = 1 \text{ min}$ | 3.4       | kV   |
| Isolation test voltage NTC          | $V_{ISOL(NTC)}$ | RMS, $f = 50 \text{ Hz}$ , $t = 1 \text{ min}$ | 3.4       | kV   |
| Material of module baseplate        |                 |                                                | Cu        |      |
| Internal isolation                  |                 | basic insulation (class 1, IEC 61140)          | $Al_2O_3$ |      |
| Creepage distance                   | $d_{Creep}$     | terminal to heatsink                           | 15.0      | mm   |
| Creepage distance                   | $d_{Creep}$     | terminal to terminal                           | 13.0      | mm   |
| Clearance                           | $d_{Clear}$     | terminal to heatsink                           | 12.5      | mm   |
| Clearance                           | $d_{Clear}$     | terminal to terminal                           | 10.0      | mm   |
| Comparative tracking index          | $CTI$           |                                                | > 200     |      |
| Relative thermal index (electrical) | $RTI$           | housing                                        | 140       | °C   |

**Table 2** Characteristic values

| Parameter                                | Symbol        | Note or test condition                                                                                                |           | Values |      |      | Unit |
|------------------------------------------|---------------|-----------------------------------------------------------------------------------------------------------------------|-----------|--------|------|------|------|
|                                          |               |                                                                                                                       |           | Min.   | Typ. | Max. |      |
| Pressure drop in cooling circuit         | $\Delta p$    | $\Delta V/\Delta t = 10.0 \text{ dm}^3/\text{min}$ , 50% water / 50% ethylenglycol, $T_F = 60 \text{ }^\circ\text{C}$ |           |        | 65   |      | mbar |
| Maximum pressure in cooling circuit      | $p$           |                                                                                                                       |           |        |      | 3    | bar  |
| Stray inductance module                  | $L_{sCE}$     |                                                                                                                       |           |        | 20   |      | nH   |
| Module lead resistance, terminals - chip | $R_{CC'+EE'}$ | $T_F = 25 \text{ }^\circ\text{C}$ , per switch                                                                        |           |        | 0.8  |      | mΩ   |
| Storage temperature                      | $T_{stg}$     |                                                                                                                       |           | -40    |      | 125  | °C   |
| Mounting torque for module mounting      | $M$           | - Mounting according to valid application note                                                                        | M5, Screw | 3      |      | 6    | Nm   |
| Terminal connection torque               | $M$           | - Mounting according to valid application note                                                                        | M6, Screw | 3      |      | 6    | Nm   |
| Weight                                   | $G$           |                                                                                                                       |           |        | 345  |      | g    |

## 2 IGBT, Inverter

**Table 3** Maximum rated values

| Parameter                 | Symbol    | Note or test condition   | Values | Unit |
|---------------------------|-----------|--------------------------|--------|------|
| Collector-emitter voltage | $V_{CES}$ | $T_{vj} = 25 \text{ °C}$ | 1700   | V    |

(table continues...)

**Table 3** (continued) Maximum rated values

| Parameter                              | Symbol     | Note or test condition              |                                                                            | Values   | Unit |
|----------------------------------------|------------|-------------------------------------|----------------------------------------------------------------------------|----------|------|
| Continuous DC collector current        | $I_{CDC}$  | $T_{vj\ max} = 175\ ^\circ\text{C}$ | $T_F = 25\ ^\circ\text{C}$                                                 | 800      | A    |
| Maximum RMS module DC-terminal current | $I_{tRMS}$ |                                     | $T_{\text{Terminal}} = 90\ ^\circ\text{C},$<br>$T_C = 90\ ^\circ\text{C}$  | 580      | A    |
|                                        |            |                                     | $T_{\text{Terminal}} = 105\ ^\circ\text{C},$<br>$T_C = 90\ ^\circ\text{C}$ | 565      |      |
| Repetitive peak collector current      | $I_{CRM}$  | $t_p$ limited by $T_{vj\ op}$       |                                                                            | 1800     | A    |
| Gate-emitter peak voltage              | $V_{GES}$  |                                     |                                                                            | $\pm 20$ | V    |

**Table 4** Characteristic values

| Parameter                            | Symbol        | Note or test condition                                                                                |                                | Values |       |      | Unit          |
|--------------------------------------|---------------|-------------------------------------------------------------------------------------------------------|--------------------------------|--------|-------|------|---------------|
|                                      |               |                                                                                                       |                                | Min.   | Typ.  | Max. |               |
| Collector-emitter saturation voltage | $V_{CE\ sat}$ | $I_C = 900\ \text{A}, V_{GE} = 15\ \text{V}$                                                          | $T_{vj} = 25\ ^\circ\text{C}$  |        | 1.67  | 1.85 | V             |
|                                      |               |                                                                                                       | $T_{vj} = 125\ ^\circ\text{C}$ |        | 1.95  |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 150\ ^\circ\text{C}$ |        | 2.02  |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 175\ ^\circ\text{C}$ |        | 2.08  |      |               |
| Gate threshold voltage               | $V_{GEth}$    | $I_C = 18.8\ \text{mA}, V_{CE} = V_{GE}, T_{vj} = 25\ ^\circ\text{C}$                                 |                                | 5.15   | 5.80  | 6.45 | V             |
| Gate charge                          | $Q_G$         | $V_{GE} = \pm 15\ \text{V}, V_{CC} = 900\ \text{V}$                                                   |                                |        | 8.59  |      | $\mu\text{C}$ |
| Internal gate resistor               | $R_{Gint}$    | $T_{vj} = 25\ ^\circ\text{C}$                                                                         |                                |        | 0.28  |      | $\Omega$      |
| Input capacitance                    | $C_{ies}$     | $f = 100\ \text{kHz}, T_{vj} = 25\ ^\circ\text{C}, V_{CE} = 25\ \text{V}, V_{GE} = 0\ \text{V}$       |                                |        | 93.8  |      | nF            |
| Reverse transfer capacitance         | $C_{res}$     | $f = 100\ \text{kHz}, T_{vj} = 25\ ^\circ\text{C}, V_{CE} = 25\ \text{V}, V_{GE} = 0\ \text{V}$       |                                |        | 0.33  |      | nF            |
| Collector-emitter cut-off current    | $I_{CES}$     | $V_{CE} = 1700\ \text{V}, V_{GE} = 0\ \text{V}$                                                       | $T_{vj} = 25\ ^\circ\text{C}$  |        |       | 35   | $\mu\text{A}$ |
| Gate-emitter leakage current         | $I_{GES}$     | $V_{CE} = 0\ \text{V}, V_{GE} = 20\ \text{V}, T_{vj} = 25\ ^\circ\text{C}$                            |                                |        |       | 100  | nA            |
| Turn-on delay time (inductive load)  | $t_{don}$     | $I_C = 900\ \text{A}, V_{CC} = 900\ \text{V},$<br>$V_{GE} = \pm 15\ \text{V}, R_{Gon} = 0.33\ \Omega$ | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.174 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                       | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.195 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 150\ ^\circ\text{C}$ |        | 0.202 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 175\ ^\circ\text{C}$ |        | 0.207 |      |               |
| Rise time (inductive load)           | $t_r$         | $I_C = 900\ \text{A}, V_{CC} = 900\ \text{V},$<br>$V_{GE} = \pm 15\ \text{V}, R_{Gon} = 0.33\ \Omega$ | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.054 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                       | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.060 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 150\ ^\circ\text{C}$ |        | 0.061 |      |               |
|                                      |               |                                                                                                       | $T_{vj} = 175\ ^\circ\text{C}$ |        | 0.065 |      |               |

(table continues...)

**Table 4** (continued) Characteristic values

| Parameter                                        | Symbol              | Note or test condition                                                                                                                                                                                                                    | Values                                                              |        |      | Unit             |
|--------------------------------------------------|---------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------|--------|------|------------------|
|                                                  |                     |                                                                                                                                                                                                                                           | Min.                                                                | Typ.   | Max. |                  |
| Turn-off delay time<br>(inductive load)          | $t_{\text{doff}}$   | $I_C = 900 \text{ A}$ , $V_{CC} = 900 \text{ V}$ ,<br>$V_{GE} = \pm 15 \text{ V}$ , $R_{\text{Goff}} = 3 \Omega$                                                                                                                          | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 0.738  |      | $\mu\text{s}$    |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 0.828  |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 0.850  |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 0.865  |      |                  |
| Fall time (inductive load)                       | $t_f$               | $I_C = 900 \text{ A}$ , $V_{CC} = 900 \text{ V}$ ,<br>$V_{GE} = \pm 15 \text{ V}$ , $R_{\text{Goff}} = 3 \Omega$                                                                                                                          | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 0.202  |      | $\mu\text{s}$    |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 0.432  |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 0.504  |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 0.573  |      |                  |
| Turn-on energy loss per<br>pulse                 | $E_{\text{on}}$     | $I_C = 900 \text{ A}$ , $V_{CC} = 900 \text{ V}$ ,<br>$L_\sigma = 25 \text{ nH}$ , $V_{GE} = \pm 15 \text{ V}$ ,<br>$R_{\text{Gon}} = 0.33 \Omega$ , $di/dt =$<br>$12300 \text{ A}/\mu\text{s}$ ( $T_{vj} = 175 \text{ }^\circ\text{C}$ ) | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 54.6   |      | mJ               |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 138    |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 172    |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 205    |      |                  |
| Turn-off energy loss per<br>pulse                | $E_{\text{off}}$    | $I_C = 900 \text{ A}$ , $V_{CC} = 900 \text{ V}$ ,<br>$L_\sigma = 25 \text{ nH}$ , $V_{GE} = \pm 15 \text{ V}$ ,<br>$R_{\text{Goff}} = 3 \Omega$ , $dv/dt = 3800$<br>$\text{V}/\mu\text{s}$ ( $T_{vj} = 175 \text{ }^\circ\text{C}$ )     | $T_{vj} = 25 \text{ }^\circ\text{C}$                                | 163    |      | mJ               |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 125 \text{ }^\circ\text{C}$                               | 245    |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 150 \text{ }^\circ\text{C}$                               | 271    |      |                  |
|                                                  |                     |                                                                                                                                                                                                                                           | $T_{vj} = 175 \text{ }^\circ\text{C}$                               | 297    |      |                  |
| SC data                                          | $I_{\text{SC}}$     | $V_{GE} = 15 \text{ V}$ , $V_{CC} = 1000 \text{ V}$ ,<br>$V_{\text{CEmax}} = V_{\text{CES}} - L_{\text{sCE}} \cdot di/dt$                                                                                                                 | $t_p \leq 8 \mu\text{s}$ ,<br>$T_{vj} = 150 \text{ }^\circ\text{C}$ | 2950   |      | A                |
|                                                  |                     |                                                                                                                                                                                                                                           | $t_p \leq 6 \mu\text{s}$ ,<br>$T_{vj} = 175 \text{ }^\circ\text{C}$ | 2850   |      |                  |
| Thermal resistance,<br>junction to cooling fluid | $R_{\text{thJF}}$   | per IGBT, $\Delta V/\Delta t = 10.0 \text{ dm}^3/\text{min}$ , 50% water /<br>50% ethylenglycol, $T_F = 60 \text{ }^\circ\text{C}$                                                                                                        |                                                                     | 0.0867 |      | K/W              |
| Temperature under<br>switching conditions        | $T_{vj \text{ op}}$ |                                                                                                                                                                                                                                           | -40                                                                 |        | 175  | $^\circ\text{C}$ |

**Note:**  $T_{vj \text{ op}} > 150 \text{ }^\circ\text{C}$  is only allowed for operation at overload conditions. For detailed specifications please refer to AN 2018-14.

### 3 Diode, Inverter

**Table 5** Maximum rated values

| Parameter                          | Symbol           | Note or test condition               | Values | Unit |
|------------------------------------|------------------|--------------------------------------|--------|------|
| Repetitive peak reverse<br>voltage | $V_{\text{RRM}}$ | $T_{vj} = 25 \text{ }^\circ\text{C}$ | 1700   | V    |

(table continues...)

**Table 5** (continued) Maximum rated values

| Parameter                       | Symbol    | Note or test condition                   | Values                    | Unit   |
|---------------------------------|-----------|------------------------------------------|---------------------------|--------|
| Continuous DC forward current   | $I_F$     |                                          | 900                       | A      |
| Repetitive peak forward current | $I_{FRM}$ | $t_P = 1 \text{ ms}$                     | 1800                      | A      |
| $I^2t$ - value                  | $I^2t$    | $t_P = 10 \text{ ms}, V_R = 0 \text{ V}$ | $T_{vj} = 125 \text{ °C}$ | $A^2s$ |
|                                 |           |                                          | $T_{vj} = 175 \text{ °C}$ |        |

**Table 6** Characteristic values

| Parameter                                     | Symbol     | Note or test condition                                                                                                                  | Values                    |       |      | Unit          |
|-----------------------------------------------|------------|-----------------------------------------------------------------------------------------------------------------------------------------|---------------------------|-------|------|---------------|
|                                               |            |                                                                                                                                         | Min.                      | Typ.  | Max. |               |
| Forward voltage                               | $V_F$      | $I_F = 900 \text{ A}, V_{GE} = 0 \text{ V}$                                                                                             | $T_{vj} = 25 \text{ °C}$  | 2.34  | 2.50 | V             |
|                                               |            |                                                                                                                                         | $T_{vj} = 125 \text{ °C}$ | 2.24  |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 150 \text{ °C}$ | 2.18  |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 175 \text{ °C}$ | 2.11  |      |               |
| Peak reverse recovery current                 | $I_{RM}$   | $V_{CC} = 900 \text{ V}, I_F = 900 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 12900 \text{ A}/\mu\text{s} (T_{vj} = 175 \text{ °C})$ | $T_{vj} = 25 \text{ °C}$  | 992   |      | A             |
|                                               |            |                                                                                                                                         | $T_{vj} = 125 \text{ °C}$ | 1130  |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 150 \text{ °C}$ | 1140  |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 175 \text{ °C}$ | 1170  |      |               |
| Recovered charge                              | $Q_r$      | $V_{CC} = 900 \text{ V}, I_F = 900 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 12900 \text{ A}/\mu\text{s} (T_{vj} = 175 \text{ °C})$ | $T_{vj} = 25 \text{ °C}$  | 119   |      | $\mu\text{C}$ |
|                                               |            |                                                                                                                                         | $T_{vj} = 125 \text{ °C}$ | 210   |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 150 \text{ °C}$ | 240   |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 175 \text{ °C}$ | 272   |      |               |
| Reverse recovery energy                       | $E_{rec}$  | $V_{CC} = 900 \text{ V}, I_F = 900 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 12900 \text{ A}/\mu\text{s} (T_{vj} = 175 \text{ °C})$ | $T_{vj} = 25 \text{ °C}$  | 86    |      | mJ            |
|                                               |            |                                                                                                                                         | $T_{vj} = 125 \text{ °C}$ | 141   |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 150 \text{ °C}$ | 159   |      |               |
|                                               |            |                                                                                                                                         | $T_{vj} = 175 \text{ °C}$ | 176   |      |               |
| Thermal resistance, junction to cooling fluid | $R_{thJF}$ | per diode, $\Delta V/\Delta t = 10.0 \text{ dm}^3/\text{min}$ , cooling fluid = 50% water / 50% ethylenglycol, $T_F = 60 \text{ °C}$    |                           | 0.135 |      | K/W           |
| Temperature under switching conditions        | $T_{vjop}$ |                                                                                                                                         | -40                       |       | 175  | °C            |

**Note:**  $T_{vjop} > 150 \text{ °C}$  is only allowed for operation at overload conditions. For detailed specifications please refer to AN 2018-14.

## 4 NTC-Thermistor

**Table 7** Characteristic values

| Parameter              | Symbol       | Note or test condition                                       | Values |      |      | Unit |
|------------------------|--------------|--------------------------------------------------------------|--------|------|------|------|
|                        |              |                                                              | Min.   | Typ. | Max. |      |
| Rated resistance       | $R_{25}$     | $T_{NTC} = 25\text{ °C}$                                     |        | 5    |      | kΩ   |
| Deviation of $R_{100}$ | $\Delta R/R$ | $T_{NTC} = 100\text{ °C}, R_{100} = 493\text{ Ω}$            | -5     |      | 5    | %    |
| Power dissipation      | $P_{25}$     | $T_{NTC} = 25\text{ °C}$                                     |        |      | 20   | mW   |
| B-value                | $B_{25/50}$  | $R_2 = R_{25} \exp[B_{25/50}(1/T_2 - 1/(298,15\text{ K}))]$  |        | 3375 |      | K    |
| B-value                | $B_{25/80}$  | $R_2 = R_{25} \exp[B_{25/80}(1/T_2 - 1/(298,15\text{ K}))]$  |        | 3411 |      | K    |
| B-value                | $B_{25/100}$ | $R_2 = R_{25} \exp[B_{25/100}(1/T_2 - 1/(298,15\text{ K}))]$ |        | 3433 |      | K    |

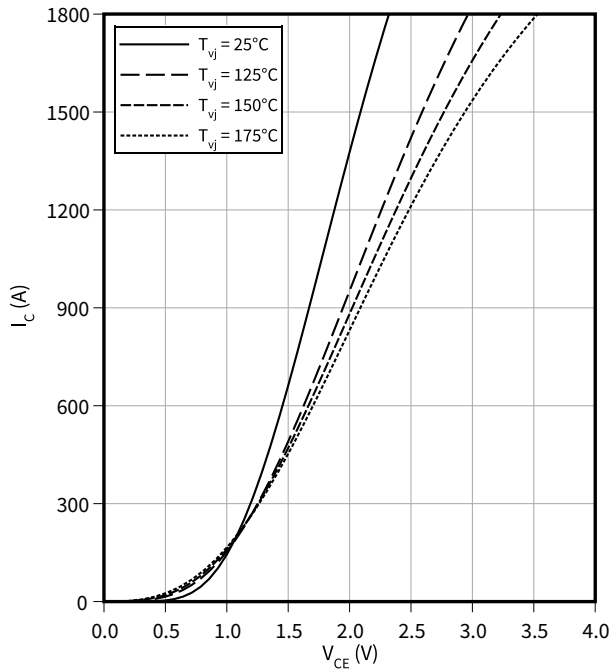
**Note:** For an analytical description of the NTC characteristics please refer to AN2009-10, chapter 4.

5 Characteristics diagrams

Output characteristic (typical), IGBT, Inverter

$I_C = f(V_{CE})$

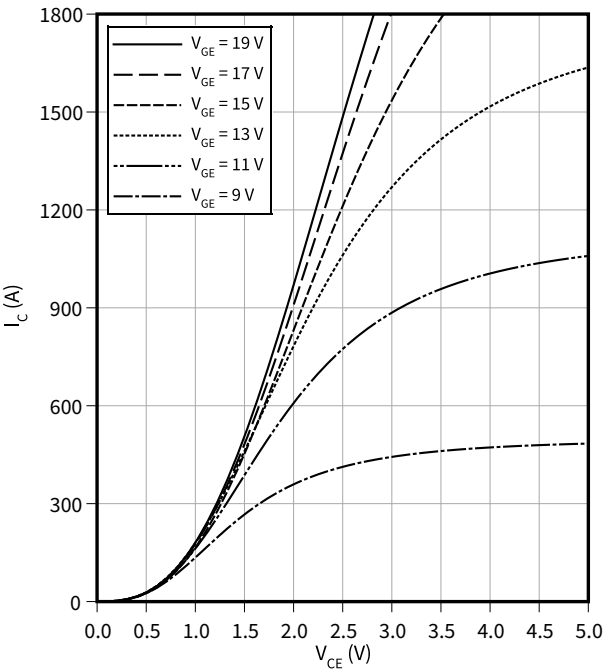
$V_{GE} = 15\text{ V}$



Output characteristic field (typical), IGBT, Inverter

$I_C = f(V_{CE})$

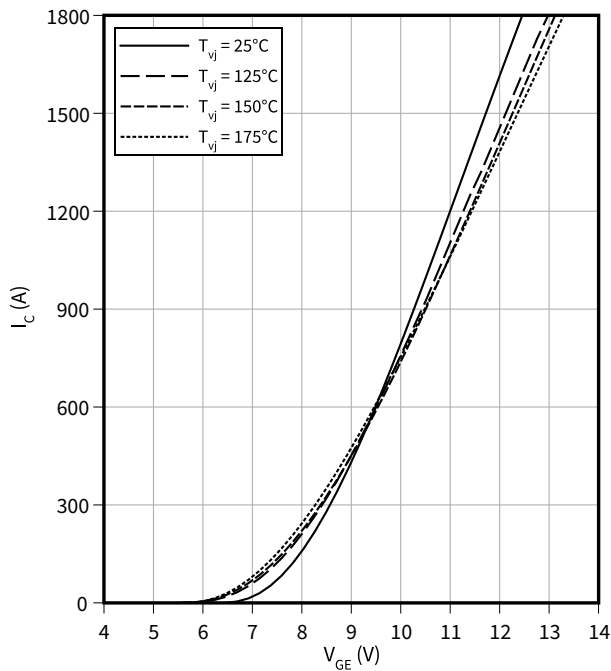
$T_{vj} = 175^\circ\text{C}$



Transfer characteristic (typical), IGBT, Inverter

$I_C = f(V_{GE})$

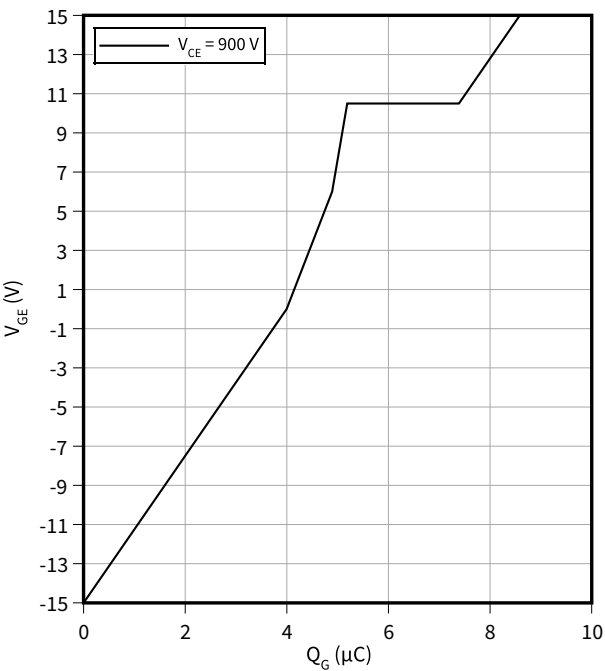
$V_{CE} = 20\text{ V}$



Gate charge characteristic (typical), IGBT, Inverter

$V_{GE} = f(Q_G)$

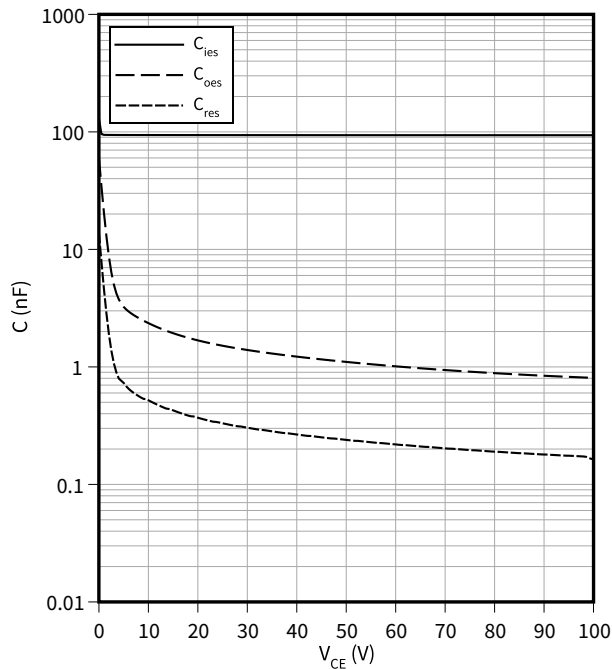
$I_C = 900\text{ A}, T_{vj} = 25^\circ\text{C}$



5 Characteristics diagrams

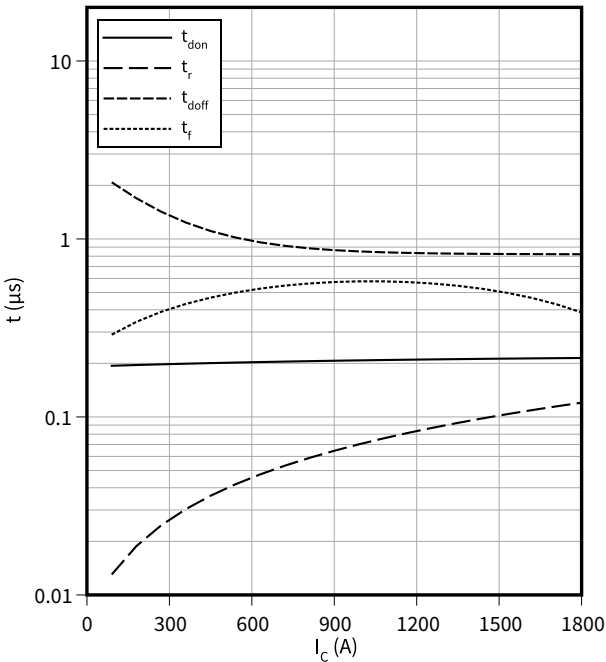
Capacity characteristic (typical), IGBT, Inverter

$C = f(V_{CE})$   
 $f = 100 \text{ kHz}$ ,  $V_{GE} = 0 \text{ V}$ ,  $T_{vj} = 25 \text{ }^{\circ}\text{C}$



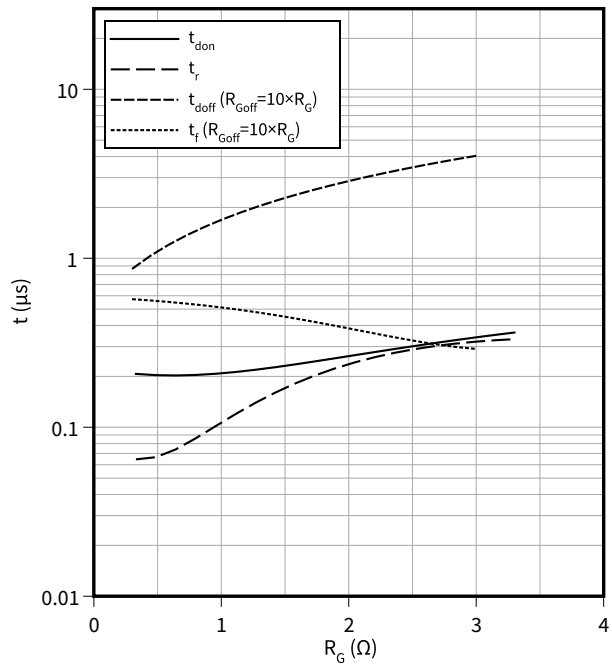
Switching times (typical), IGBT, Inverter

$t = f(I_C)$   
 $R_{Goff} = 3 \text{ } \Omega$ ,  $R_{Gon} = 0.33 \text{ } \Omega$ ,  $V_{CC} = 900 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 175 \text{ }^{\circ}\text{C}$



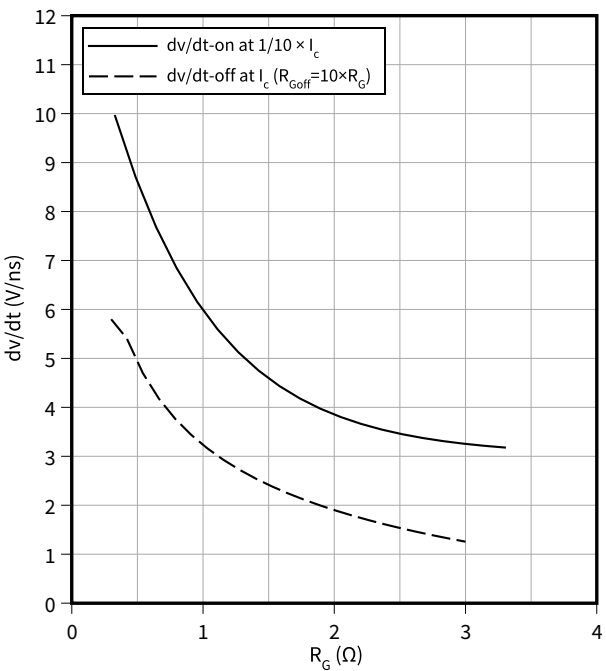
Switching times (typical), IGBT, Inverter

$t = f(R_G)$   
 $I_C = 900 \text{ A}$ ,  $V_{CC} = 900 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 175 \text{ }^{\circ}\text{C}$



Voltage slope (typical), IGBT, Inverter

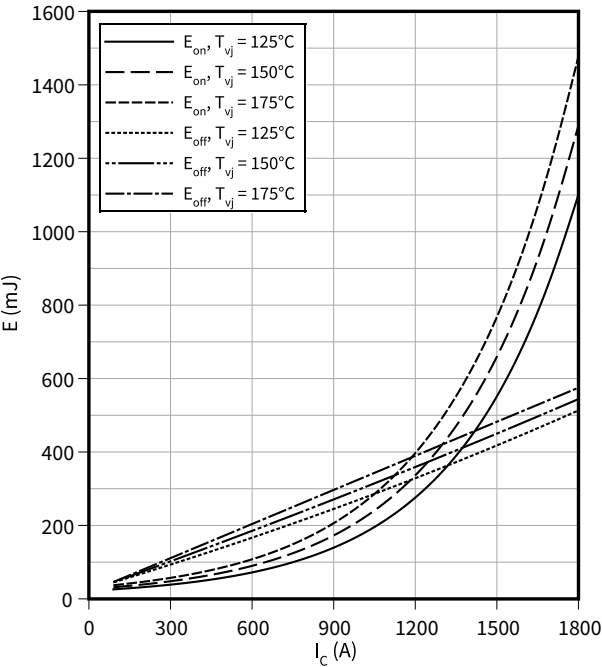
$dv/dt = f(R_G)$   
 $I_C = 900 \text{ A}$ ,  $V_{CE} = 900 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 25 \text{ }^{\circ}\text{C}$



5 Characteristics diagrams

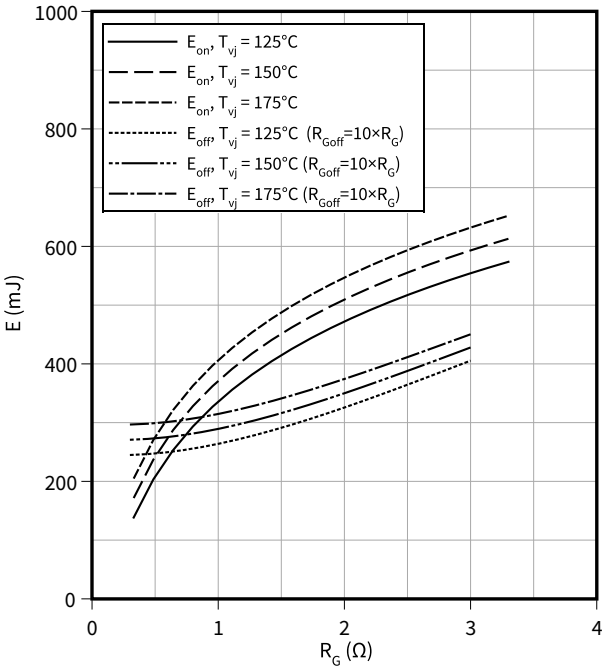
Switching losses (typical), IGBT, Inverter

$E = f(I_C)$   
 $R_{Goff} = 3 \Omega$ ,  $R_{Gon} = 0.33 \Omega$ ,  $V_{CC} = 900 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$



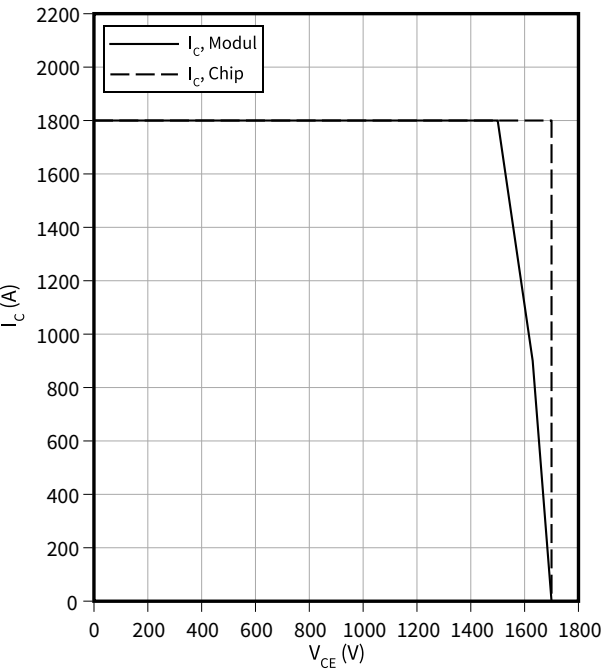
Switching losses (typical), IGBT, Inverter

$E = f(R_G)$   
 $I_C = 900 \text{ A}$ ,  $V_{CC} = 900 \text{ V}$ ,  $V_{GE} = \pm 15 \text{ V}$



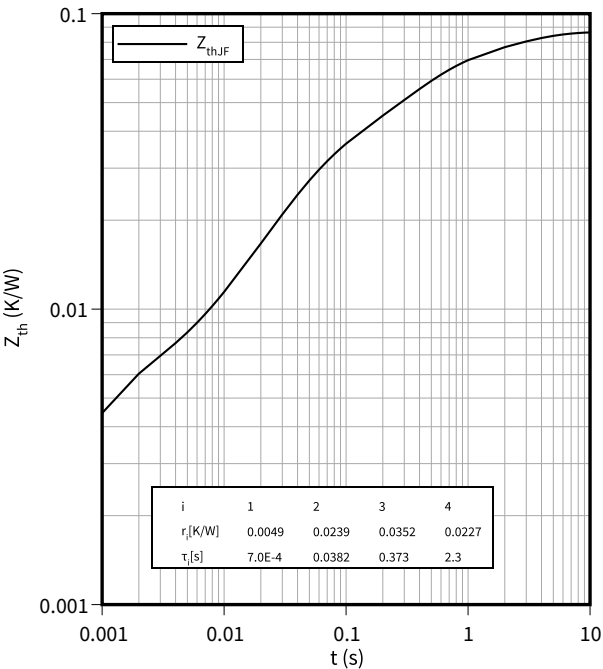
Reverse bias safe operating area (RBSOA), IGBT, Inverter

$I_C = f(V_{CE})$   
 $R_{Goff} = 3 \Omega$ ,  $V_{GE} = \pm 15 \text{ V}$ ,  $T_{vj} = 175 \text{ °C}$



Transient thermal impedance, IGBT, Inverter

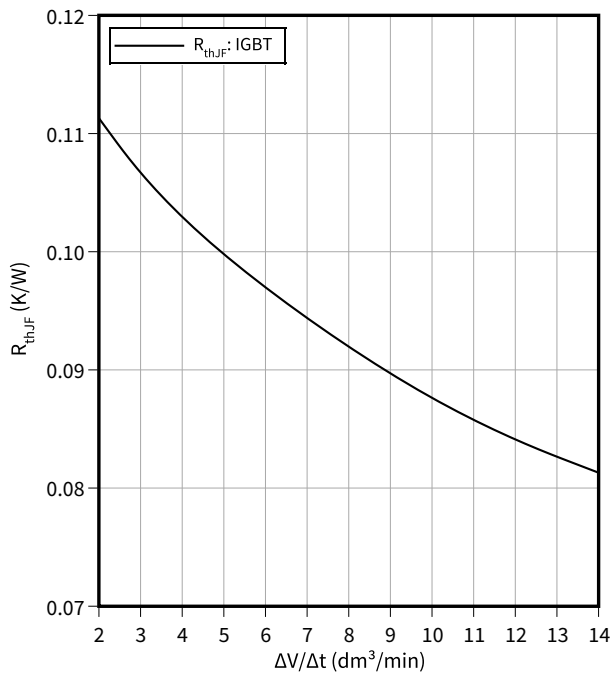
$Z_{th} = f(t)$



5 Characteristics diagrams

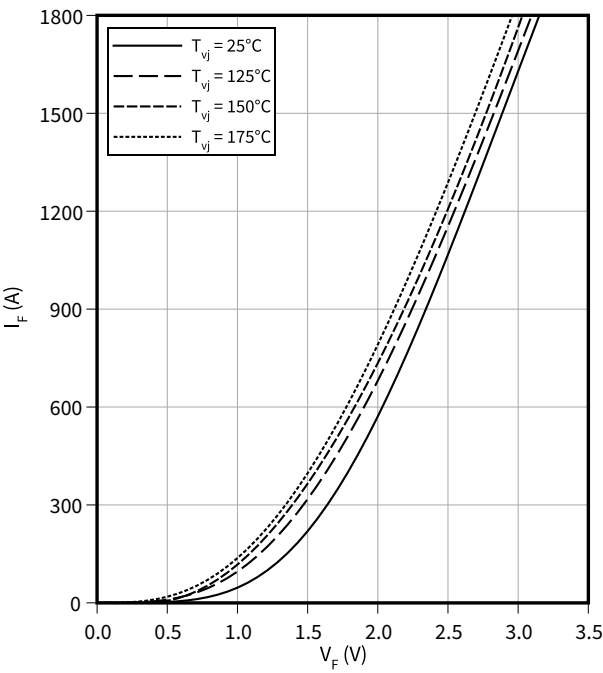
Thermal impedance, IGBT, Inverter

$R_{thJF} = f(\Delta V/\Delta t)$



Forward characteristic (typical), Diode, Inverter

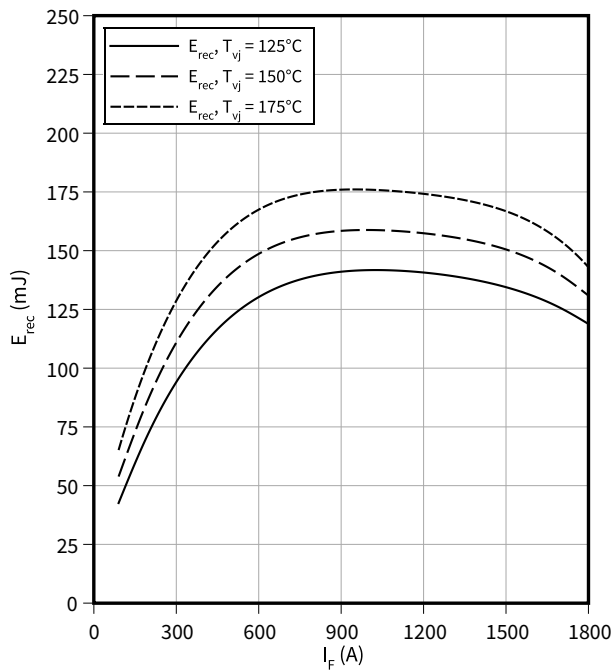
$I_F = f(V_F)$



Switching losses (typical), Diode, Inverter

$E_{rec} = f(I_F)$

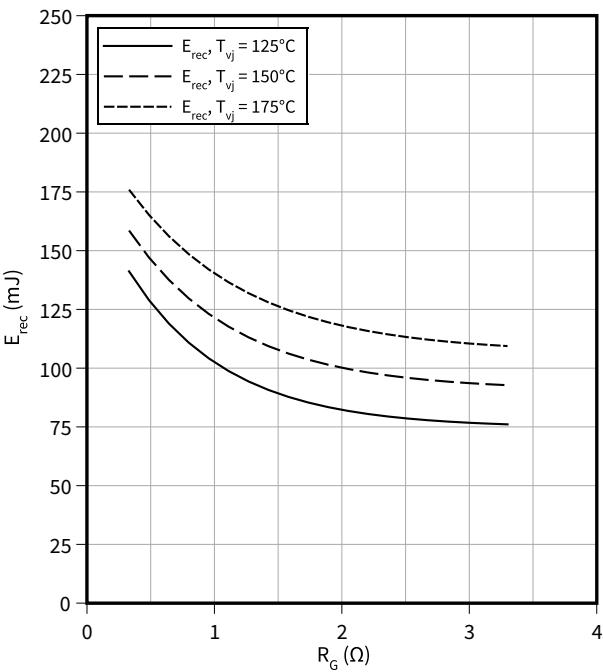
$R_{Gon} = 0.33 \Omega$ ,  $V_{CE} = 900 V$



Switching losses (typical), Diode, Inverter

$E_{rec} = f(R_G)$

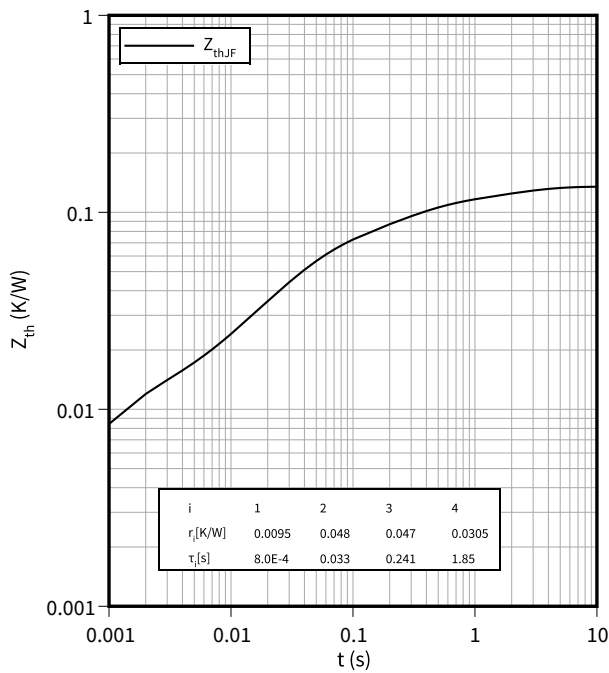
$V_{CE} = 900 V$ ,  $I_F = 900 A$



5 Characteristics diagrams

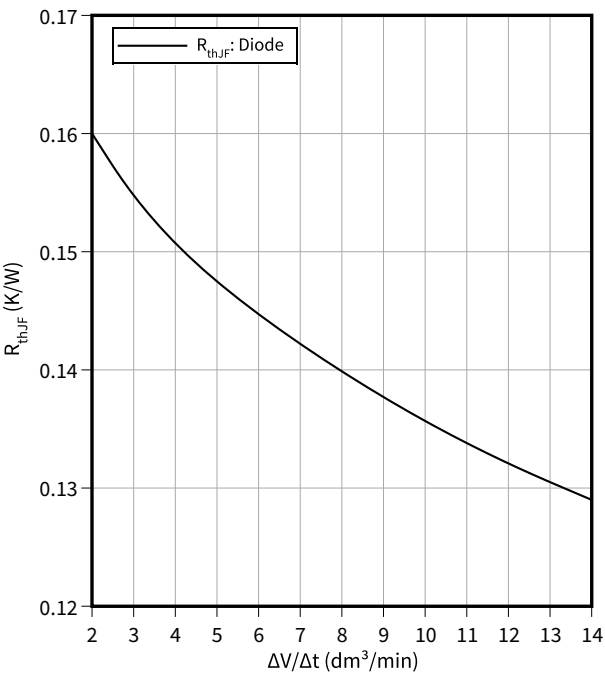
Transient thermal impedance, Diode, Inverter

$Z_{th} = f(t)$



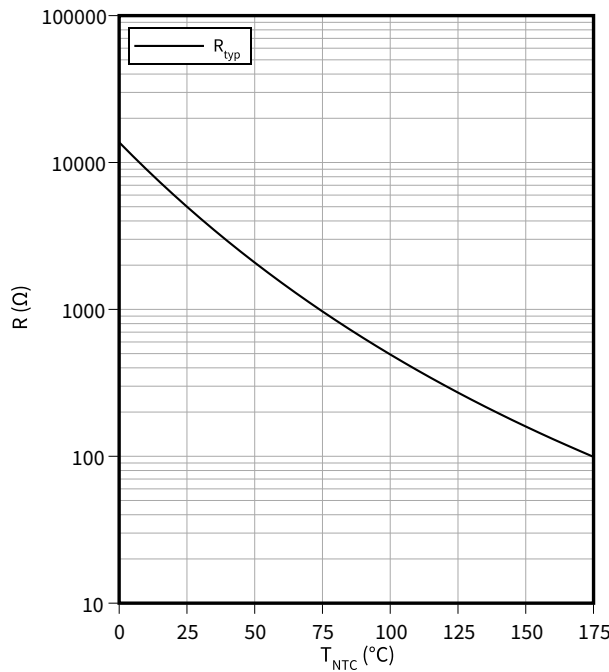
Thermal impedance, Diode, Inverter

$R_{thJF} = f(\Delta V/\Delta t)$



Temperature characteristic (typical), NTC-Thermistor

$R = f(T_{NTC})$



6 Circuit diagram

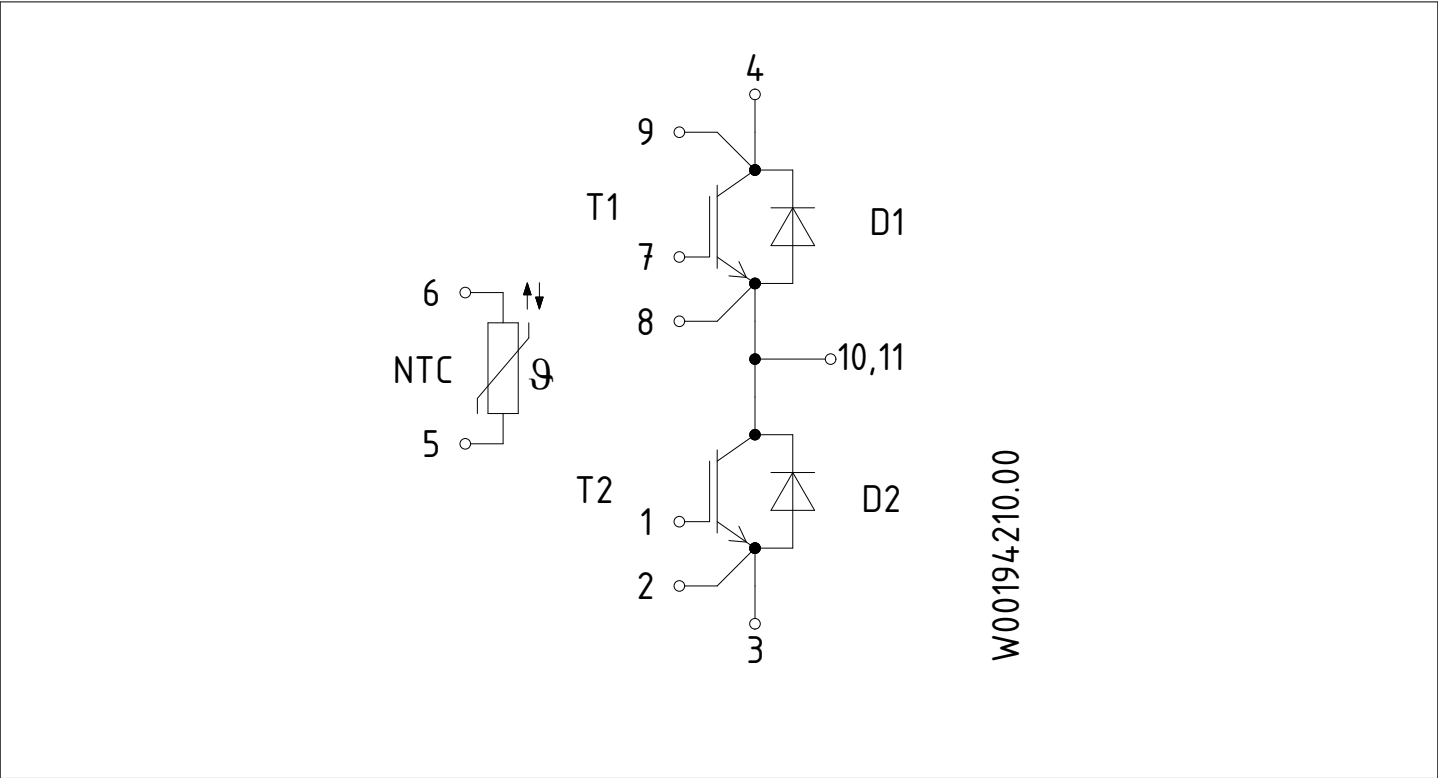


Figure 1

## 7 Package outlines

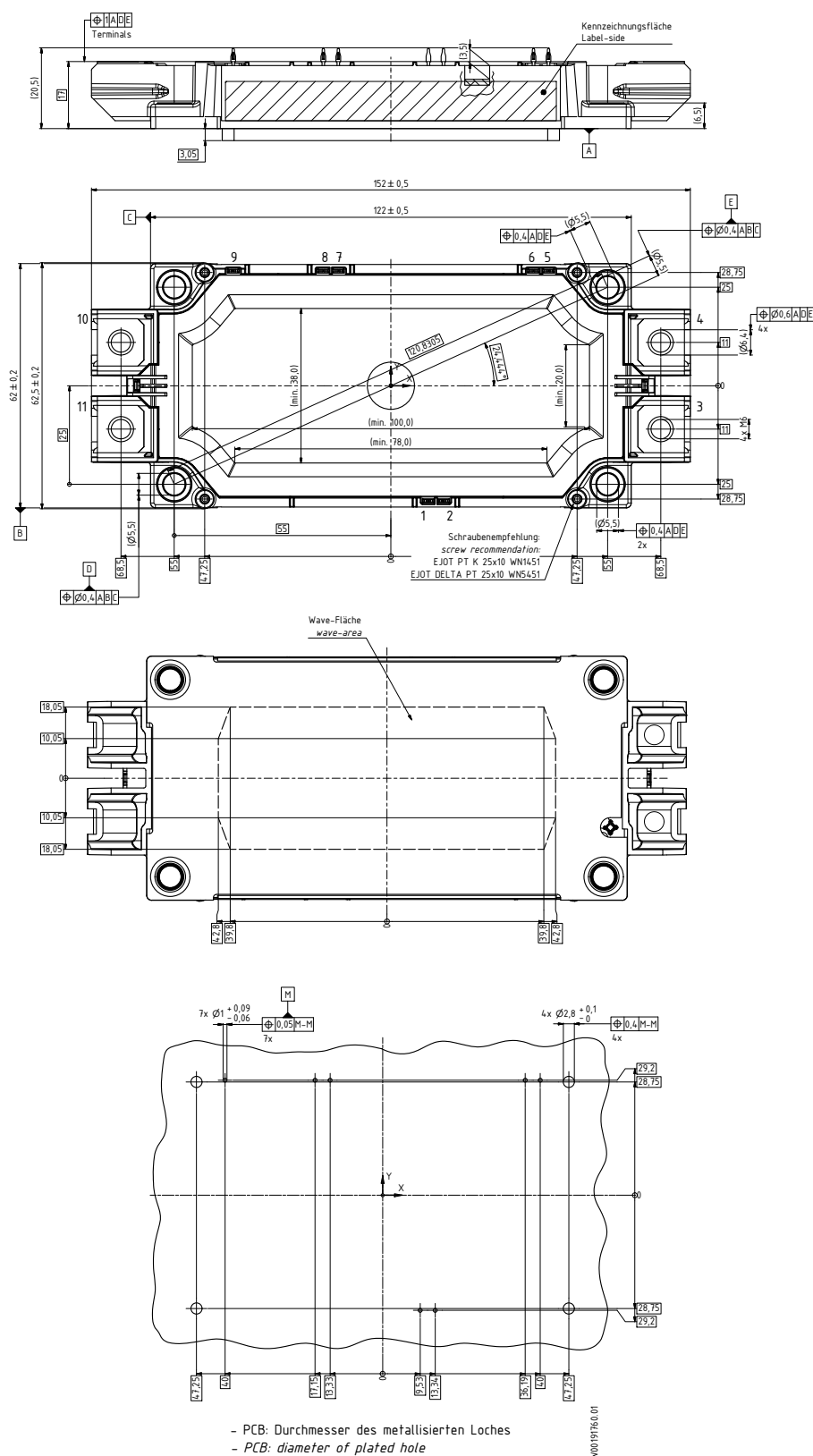


Figure 2

8 Module label code

| Module label code       |                                                                                     |                         |                 |
|-------------------------|-------------------------------------------------------------------------------------|-------------------------|-----------------|
| Code format             | Data Matrix                                                                         |                         | Barcode Code128 |
| Encoding                | ASCII text                                                                          |                         | Code Set A      |
| Symbol size             | 16x16                                                                               |                         | 23 digits       |
| Standard                | IEC24720 and IEC16022                                                               |                         | IEC8859-1       |
| Code content            | <i>Content</i>                                                                      | <i>Digit</i>            | <i>Example</i>  |
|                         | Module serial number                                                                | 1 – 5                   | 71549           |
|                         | Module material number                                                              | 6 - 11                  | 142846          |
|                         | Production order number                                                             | 12 - 19                 | 55054991        |
|                         | Date code (production year)                                                         | 20 – 21                 | 15              |
|                         | Date code (production week)                                                         | 22 – 23                 | 30              |
| Example                 |   |                         |                 |
|                         |  |                         |                 |
| 71549142846550549911530 |                                                                                     | 71549142846550549911530 |                 |

Figure 3



Revision history

Revision history

| Document revision | Date of release | Description of changes |
|-------------------|-----------------|------------------------|
| 1.00              | 2023-11-21      | Initial version        |

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**Edition 2023-11-21**

**Published by**

**Infineon Technologies AG**  
**81726 Munich, Germany**

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**Email:** [erratum@infineon.com](mailto:erratum@infineon.com)

**Document reference**  
**IFX-ABI486-001**

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